

RELIABILITY REPORT FOR MAX16032ETM+ PLASTIC ENCAPSULATED DEVICES

April 27, 2010

MAXIM INTEGRATED PRODUCTS

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Conclusion

The MAX16032ETM+ successfully meets the quality and reliability standards required of all Maxim products. In addition, Maxim's continuous reliability monitoring program ensures that all outgoing product will continue to meet Maxim's quality and reliability standards.

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I. Device Description

A. General

The MAX16031/MAX16032 EEPROM-configurable system monitors feature an integrated 10-bit analog-to-digital converter (ADC) designed to monitor voltages, temperatures, and current in complex systems. These EEPROM-configurable devices allow enormous flexibility in selecting operating ranges, upper and lower limits, fault output configuration, and operating modes with the capability of storing these values within the device. The MAX16031 monitors up to eight voltages, three temperatures (one internal/two external remote temperature diodes), and a single current. The MAX16032 monitors up to six voltages and two temperatures (one internal/one remote temperature diode). Each of these monitored parameters is muxed into the ADC and written to its respective register that can be read back through the SMBus(tm) and JTAG interface. Measured values are compared to the user-configurable upper and lower limits. For voltage measurements, there are two undervoltage and two overvoltage limits. For current and temperature, there are two sets of upper limits. Whenever the measured value is outside its limits, an alert signal is generated to notify the processor. Independent outputs are available for overcurrent, overtemperature, and undervoltage/overvoltage that are configured to assert on assigned channels. There are also undedicated fault outputs that are configured to offer a secondary limit for temperature, current, or voltage fault or provide a separate overvoltage output. During a major fault event, such as a system shutdown, the MAX16031/MAX16032 automatically copy the internal ADC registers into the nonvolatile EEPROM registers that then are read back for diagnostic purposes. The MAX16031/MAX16032 offer additional GPIOs that are used for voltage sequencing, additional fault outputs, a manual reset input, or read/write logic levels. A separate current-sense amplifier with an independent output allows for fast shutoff during overcurrent conditions. The MAX16031/MAX16032 are available in a 7mm x 7mm TQFN package and are fully



A. Description/Function:	EEPROM-Based System Monitors with Nonvolatile Fault Memory
B. Process:	EB8
C. Number of Device Transistors:	1700
D. Fabrication Location:	California or Texas
E. Assembly Location:	China, Thailand

October 26, 2007

F. Date of Initial Production:

III. Packaging Information

A. Package Type:	48-pin TQFN 7x7
B. Lead Frame:	Copper
C. Lead Finish:	100% matte Tin
D. Die Attach:	Conductive
E. Bondwire:	Au (1 mil dia.)
F. Mold Material:	Epoxy with silica filler
G. Assembly Diagram:	#05-9000-2820
H. Flammability Rating:	Class UL94-V0
 Classification of Moisture Sensitivity per JEDEC standard J-STD-020-C 	Level 1
J. Single Layer Theta Ja:	36°C/W
K. Single Layer Theta Jc:	0.8°C/W
L. Multi Layer Theta Ja:	25°C/W
M. Multi Layer Theta Jc:	0.8°C/W

IV. Die Information

A. Dimensions:	184 X 213 mils
B. Passivation:	Si_3N_4/SiO_2 (Silicon nitride/ Silicon dioxide)
C. Interconnect:	AI/0.5%Cu with Ti/TiN Barrier
D. Backside Metallization:	None
E. Minimum Metal Width:	3.0 microns (as drawn)
F. Minimum Metal Spacing:	3.0 microns (as drawn)
G. Bondpad Dimensions:	5 mil. Sq.
H. Isolation Dielectric:	SiO ₂
I. Die Separation Method:	Wafer Saw



V. Quality Assurance Information

A.	Quality Assurance Contacts:	Don Lipps (Manager, Reliability Engineering) Bryan Preeshl (Managing Director of QA)
В.	Outgoing Inspection Level:	0.1% for all electrical parameters guaranteed by the Datasheet.0.1% For all Visual Defects.
C.	Observed Outgoing Defect Rate:	< 50 ppm
D.	Sampling Plan:	Mil-Std-105D

VI. Reliability Evaluation

A. Accelerated Life Test

The results of the 135°C biased (static) life test are shown in Table 1. Using these results, the Failure Rate (λ) is calculated as follows:

 $\lambda = \underbrace{1}_{\text{MTTF}} = \underbrace{\frac{1.83}{192 \times 4340 \times 48 \times 2}}_{\text{(where 4340 = Temperature Acceleration factor assuming an activation energy of 0.8eV)}$ $\lambda = 22.9 \times 10^{-9}$ $\lambda = 22.9 \text{ F.I.T. (60\% confidence level @ 25°C)}$

The following failure rate represents data collected from Maxim's reliability monitor program. Maxim performs quarterly life test monitors on its processes. This data is published in the Reliability Report found at http://www.maxim-ic.com/qa/reliability/monitor. Cumulative monitor data for the EB8 Process results in a FIT Rate of 0.09 @ 25C and 1.58 @ 55C (0.8 eV, 60% UCL)

B. Moisture Resistance Tests

The industry standard 85°C/85%RH or HAST testing is monitored per device process once a quarter.

C. E.S.D. and Latch-Up Testing

The MS99-1 die type has been found to have all pins able to withstand a HBM transient pulse of +/-2000V per JEDEC JESD22-A114. Latch-Up testing has shown that this device withstands a current of +/-250mA.



Table 1 Reliability Evaluation Test Results

MAX16032ETM+

TEST ITEM	TEST CONDITION	FAILURE IDENTIFICATION	SAMPLE SIZE	NUMBER OF FAILURES	
Static Life Test	(Note 1)				
	Ta = 135°C	DC Parameters	48	0	
	Biased	& functionality			
	Time = 192 hrs.				
Moisture Testing	(Note 2)				
HAST	Ta = 130°C	DC Parameters	77	0	
	RH = 85%	& functionality			
	Biased				
	Time = 96hrs.				
Mechanical Stres	ss (Note 2)				
Temperature	-65°C/150°C	DC Parameters	77	0	
Cycle	1000 Cycles	& functionality			
	Method 1010	-			

Note 1: Life Test Data may represent plastic DIP qualification lots.

Note 2: Generic Package/Process data